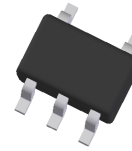


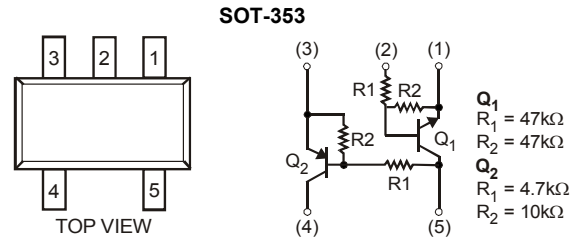
Features

- Epitaxial Planar Die Construction
- Surface Mount Package Suited for Automated Assembly
- Simplifies Circuit Design and Reduces Board Space
- **Lead Free/RoHS Compliant (Note 1)**
- **"Green" Device (Note 2)**



Mechanical Data

- Case: SOT-353
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed Over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)



Schematic and Pin Configuration

Maximum Ratings, Total Device @_{T_A} = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	P _D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	R _{θJA}	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Maximum Ratings, Pre-Biased NPN Transistor, Q₁ @_{T_A} = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	50	V
Input Voltage	V _{IN}	-10 to +40	V
Output Current	I _O	30	mA
Collector Current	I _{C(MAX)}	100	mA

Maximum Ratings, Pre-Biased PNP Transistor, Q₂ @_{T_A} = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	-50	V
Input Voltage	V _{IN}	-20 to +7	V
Output Current	I _O	-100	mA
Collector Current	I _{C(MAX)}	-100	mA

- Notes:
1. No purposefully added lead.
 2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.
 3. Device mounted on FR-4 PCB; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics, Pre-Biased NPN Transistor, Q₁ @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	—	—	0.5	V	V _{CC} = 5V, I _O = 100μA
	V _{I(on)}	3	—	—	V	V _O = 0.3V, I _O = 2mA
Output Voltage	V _{O(on)}	—	0.1	0.3	V	I _O /I _I = 10mA/0.5 mA
Input Current	I _I	—	—	0.18	mA	V _I = 5V
Output Current	I _{O(off)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	G _I	68	—	—	—	V _O = 5V, I _O = 5mA
Gain-Bandwidth Product	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz*
Input Resistance	R ₁	32.9	47	61.1	kΩ	—
Resistance Ratio	R ₂ /R ₁	0.8	1	1.2	—	—

*Characteristics of Transistor – for reference only.

Electrical Characteristics, Pre-Biased PNP Transistor, Q₂ @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V _{I(off)}	—	—	-0.3	V	V _{CC} = -5V, I _O = -100μA
	V _{I(on)}	-2.5	—	—	V	V _O = -0.3V, I _O = -20mA
Output Voltage	V _{O(on)}	—	-0.1	-0.3	V	I _O /I _I = -10mA/-0.5 mA
Input Current	I _I	—	—	-1.8	mA	V _I = -5V
Output Current	I _{O(off)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	G _I	30	—	—	—	V _O = -5V, I _O = -10mA
Gain-Bandwidth Product	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz*
Input Resistance	R ₁	3.29	4.7	6.11	kΩ	—
Resistance Ratio	R ₂ /R ₁	1.7	2.1	2.6	—	—

*Characteristics of Transistor – for reference only.

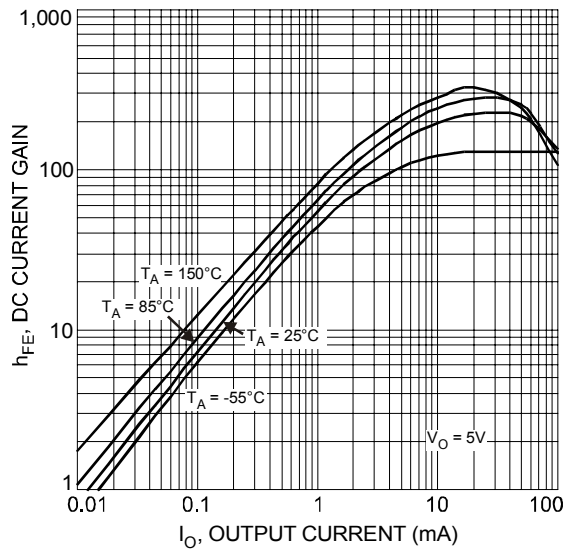


Fig. 1 Typical DC Current Gain vs. Output Current (Q₁, NPN)

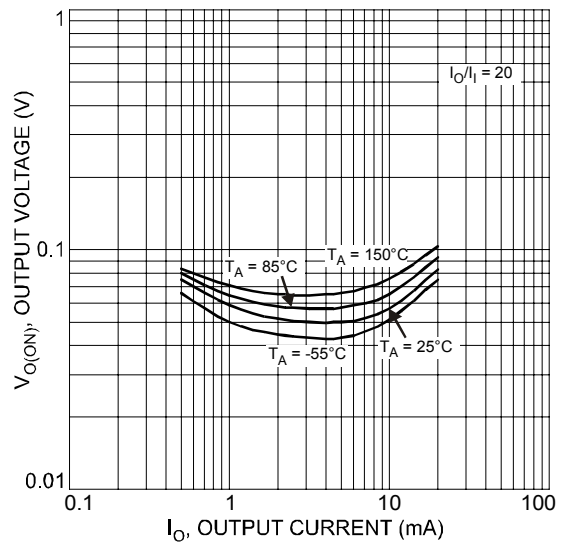


Fig. 2 Typical Output Voltage vs. Output Current (Q₁, NPN)

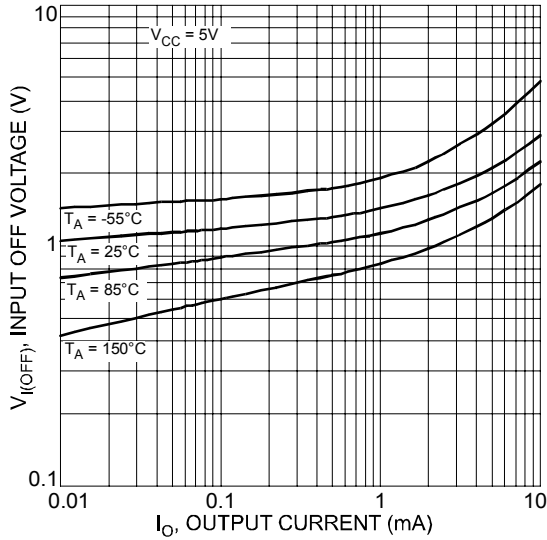


Fig. 3 Typical Input OFF Voltage vs. Output Current (Q1, NPN)

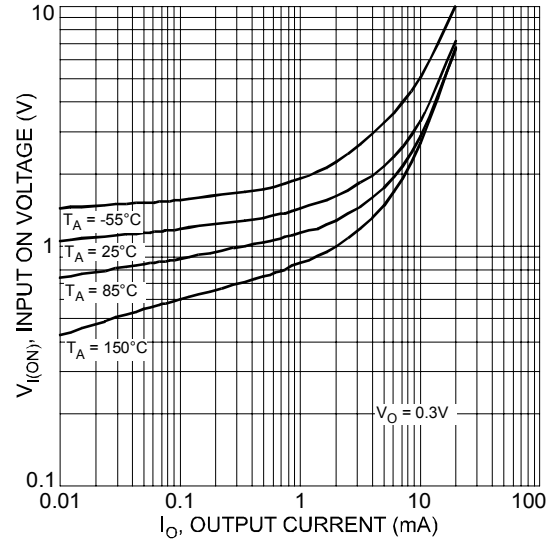


Fig. 4 Typical Input ON Voltage vs. Output Current (Q1, NPN)

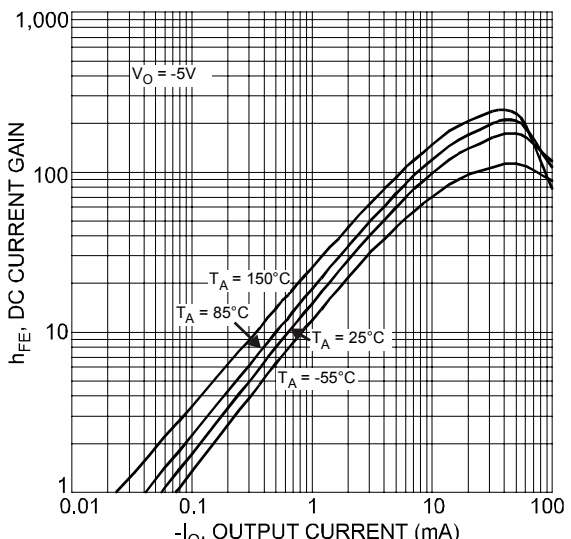


Fig. 5 Typical DC Current Gain vs. Output Current (Q2, PNP)

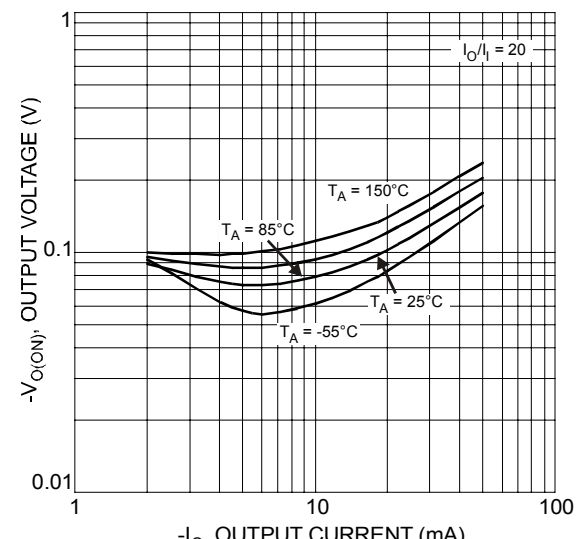


Fig. 6 Typical Output Voltage vs. Output Current (Q2, PNP)

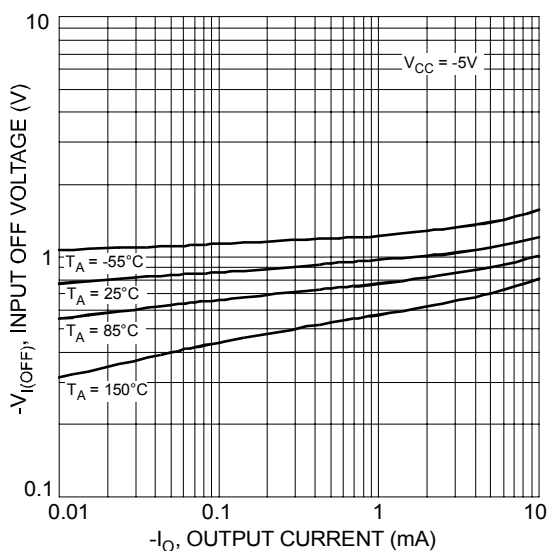


Fig. 7 Typical Input Off Voltage vs. Output Current (Q2, PNP)

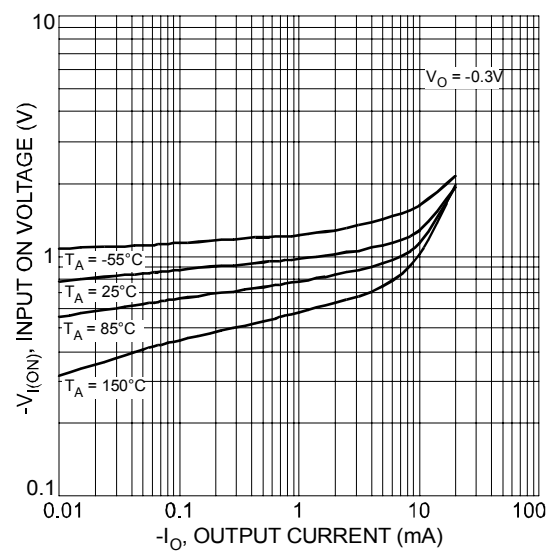


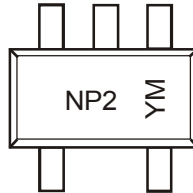
Fig. 8 Typical Input ON Voltage vs. Output Current (Q2, PNP)

Ordering Information (Note 4)

Device	Packaging	Shipping
UMC5N-7	SOT-353	3000/Tape & Reel

Notes: 4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



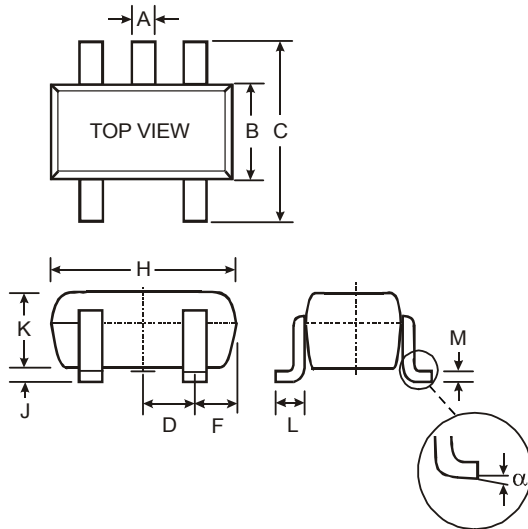
NP2 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year ex: U = 2007
 M = Month ex: 9 = September

Date Code Key

Year	2007	2008	2009	2010	2011	2012
Code	U	V	W	X	Y	Z

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SOT-353		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

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